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Panasonic Electronic Components
CNA1007H

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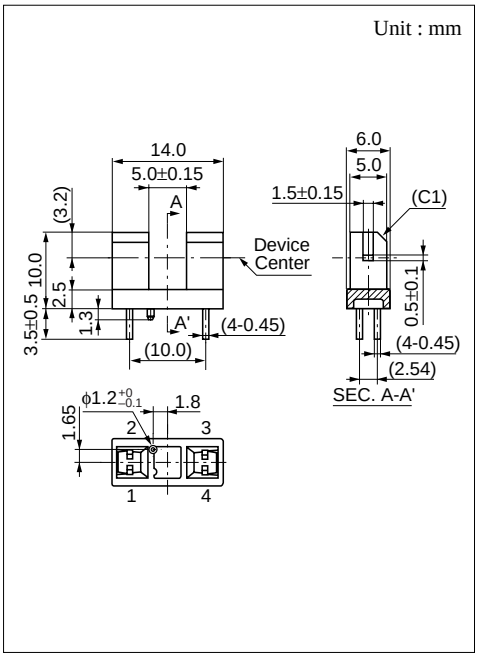
CNA1007H

Photo Interrupter

For contactless SW, object detection



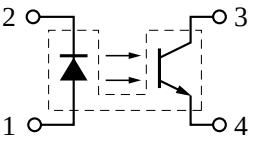
Overview

CNA1007H is a transmissive photosensor in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a high sensitivity phototransistor is used as the light detecting element. The two elements are arranged so as to face each other, and objects passing between them are detected.

Features

- Position detection accuracy : 0.3 mm
- Gap width : 5 mm
- Horizontal slit type
- The type directly attached to PCB (with a positioning pins)

Internal connector



Pin connection

Absolute Maximum Ratings (Ta = 25˚C)

Parameter		Symbol	Ratings	Unit
Input (Light emitting diode)	Reverse voltage (DC)	V_R	5	V
	Forward current (DC)	I_F	50	mA
	Power dissipation	P_D *1	75	mW
Output (Photo transistor)	Collector current	I_C	20	mA
	Collector to emitter voltage	V_{CEO}	30	V
	Emitter to collector voltage	V_{ECO}	5	V
	Collector power dissipation	P_C *2	100	mW
Temperature	Operating ambient temperature	T_{opr}	–25 to +85	˚C
	Storage temperature	T_{stg}	– 40 to +100	˚C

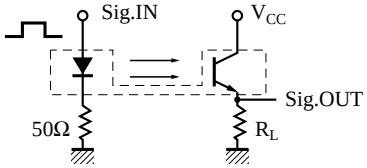
*1 Input power derating ratio is 1.0 mW/˚C at Ta = 25˚C.

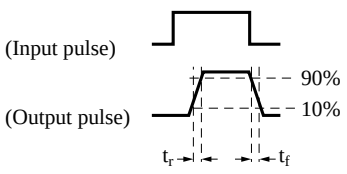
*2 Output power derating ratio is 1.33 mW/˚C at Ta = 25˚C.

Electrical Characteristics (Ta = 25˚C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Input characteristics	Forward voltage (DC)	V_F	I_F = 20mA		1.25	1.4	V
	Reverse current (DC)	I_R	V_R = 3V			10	µA
Output characteristics	Collector cutoff current	I_{CEO}	V_{CE} = 10V			200	nA
Transfer characteristics	Collector current	I_C	V_{CE} = 5V, I_F = 20mA	0.5		14	mA
	Collector to emitter saturation voltage	$V_{CE(sat)}$	I_F = 40mA, I_C = 1mA			0.4	V
	Response time	t_r , t_f *	V_{CC} = 5V, I_C = 1mA, R_L = 100Ω		5		µs

* Switching time measurement circuit



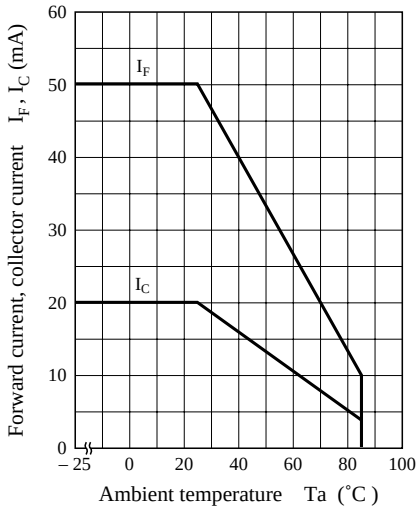


t_r : Rise time (Time required for the collector current to increase from 10% to 90% of its final value)

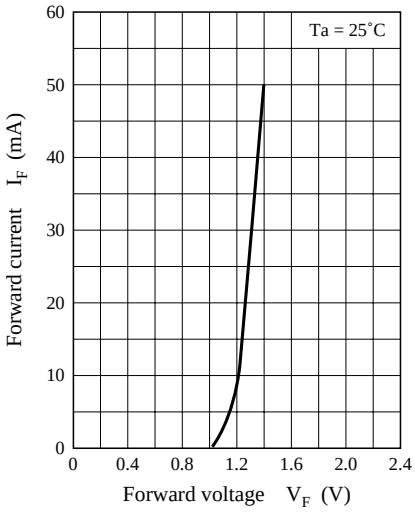
t_f : Fall time (Time required for the collector current to decrease from 90% to 10% of its initial value)

CNA1007H Transmissive Photosensors (Photo Interrupters)

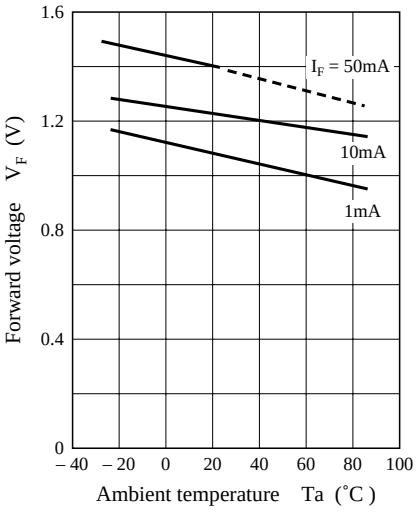
I_F , I_C — Ta



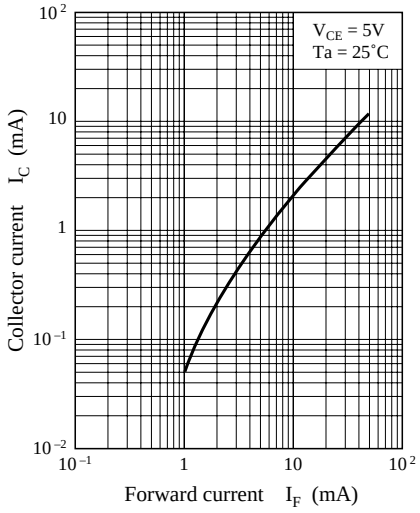
I_F — V_F



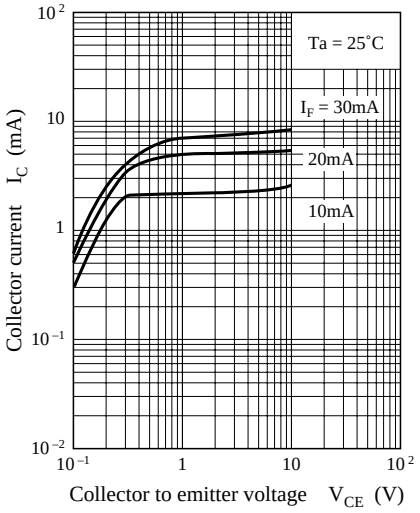
V_F — Ta



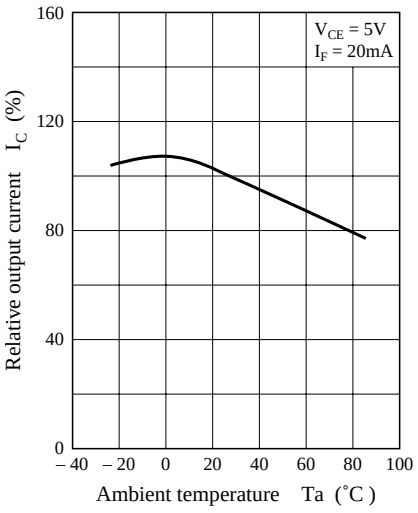
I_C — I_F



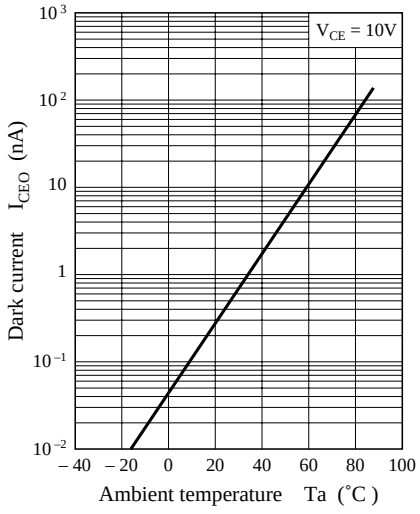
I_C — V_{CE}



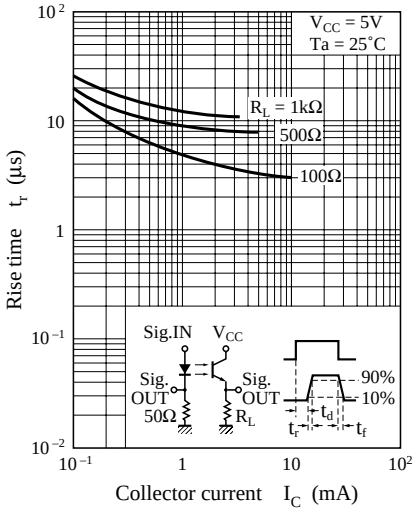
I_C — Ta



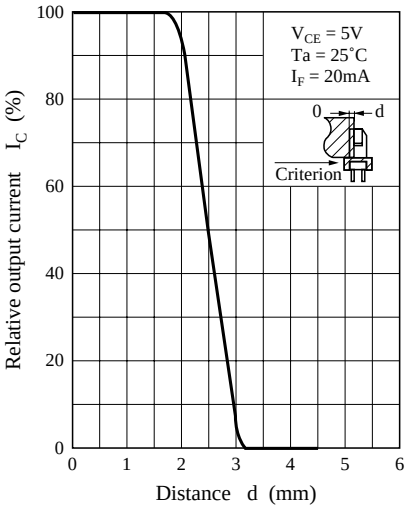
I_{CEO} — Ta



t_r — I_C



I_C — d



Transmissive Photosensors (Photo Interrupters) CNA1007H

I_C — d